TOSHIBA Bi-CMOS Linear Integrated Circuit Silicon Monolithic

TB2929HQ

45W × 4-ch BTL Audio Power IC

The TB29ggHQ is a four-channel BTL power amplifier for car audio applications.

This IC has a pure complementary P-ch and N-ch DMOS output stage, offering maximum output power (POUT MAX) of 45 W.

It includes a standby switch, mute function and various protection features.

Features

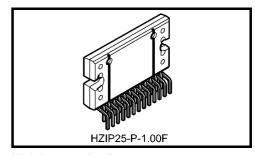
- High output power
 - POUT MAX (1) = 45 W (typ.) (V_{CC} = 15.2 V, f = 1 kHz, JEITA max, R_L = 4 Ω)
 - Pout MAX (2) = 41 W (typ.) $(V_{CC} = 14.4 \text{ V}, f = 1 \text{ kHz}, \text{JEITA max}, R_L = 4 \Omega)$
 - P_{OUT} (1) = 24 W (typ.) (V_{CC} = 14.4 V, f = 1 kHz, THD = 10%, R_L = 4 Ω)
 - P_{OUT} (2) = 21 W (typ.) (V_{CC} = 13.2 V, f = 1 kHz, THD = 10%, R_L = 4 Ω)
- Low THD: 0.007% (typ.) (V_{CC} = 13.2 V, f = 1 kHz, P_{OUT} = 5 W, R_L = 4 Ω)
- Low noise: V_{NO} = 60 μV_{rms} (typ.) (V_{CC} = 13.2 V, R_g = 0 Ω , BW = 20 Hz to 20 kHz, R_L = 4 Ω)
- Standby switch (pin 4)
- Mute function (pin 22)
- Built-in AUX amplifier from single input to 2 channels output (pin 25)
- Various protection features

 Thermal overload: overvoltage: output short.

 $Thermal\ overload;\ overvoltage;\ output\ short-circuits\ to\ GND,\ V_{CC}\ and\ across\ the\ load;\ speaker\ current\ limiting$

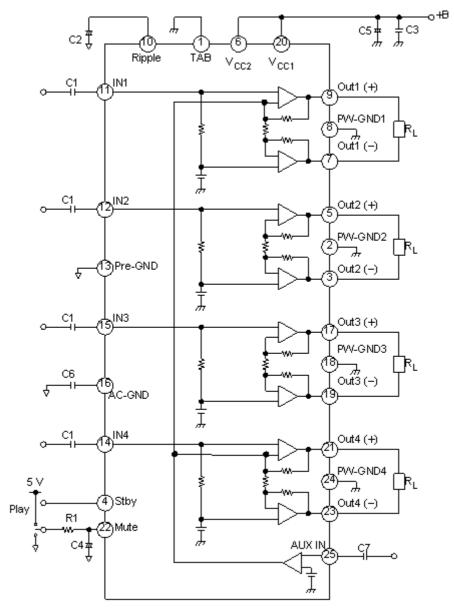
- Operating supply voltage: V_{CC} (opr) = 8.0 to 18 V ($R_L = 4~\Omega$)
 - Note 1: Install the device correctly. Otherwise, the device or system may be degraded, damaged or even destroyed.
 - Note 2: The protection features are intended to avoid output short-circuits or other abnormal conditions temporarily. It is not guaranteed that they will prevent the IC from being damaged.

 Exposure to conditions beyond the guaranteed operating ranges may not activate the protection features, resulting in an IC damage due to output short-circuits.



Weight: 7.7 g (typ.)

Block Diagram



Some of the functional blocks, circuits or constants may be omitted from the block diagram or simplified for explanatory purposes.

Detailed Description

1. Standby Switch (pin 4)

The power supply can be turned on or off via pin 4 (Stby). The threshold voltage of pin 4 is set at about 3 V_{BE} (typ.). The power supply current is about 0.01 μA (typ.) in the standby state.

Standby Control Voltage (VSB): Pin 4

Standby	Power	V _{SB} (V)
ON	OFF	0 to 0.9
OFF	ON	2.9 to VCC

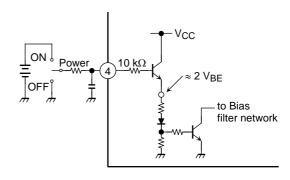


Figure 1 Setting Pin 4 High Turns on

Check the pop levels when the time constant of pin 4 is changed.

Benefits of the Standby Switch

- (1) VCC can be directly turned on or off by a microcontroller, eliminating the need for a switching relay.
- (2) Since the control current is minuscule, a low-current-rated switching relay can be used.

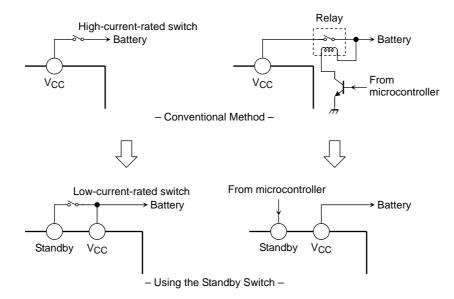
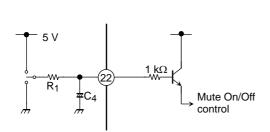


Figure 2 Standby Switch

2. Mute Function (pin 22)

The audio mute function is enabled by setting pin 22 Low. R_1 and C_4 determine the time constant of the mute function. The time constant affects pop noise generated when power or the mute function is turned on or off; thus, it must be determined on a per-application basis. (Refer to Figures 4 and 5.) The value of the external pull-up resistor is determined, based on pop noise value.

For example, when the control voltage is changed from 5 V to 3.3 V, the pull-up resistor should be: 3.3 V/5 V \times 47 $k\Omega$ = 31 $k\Omega$



20 V_{CC} = 13.2 V f = 1 kHz R_L = 4 Ω V_O = 20dBm BW = 400 Hz to 30 kHz P₋₁₀₀ -60 -80 -100 -120 0 0.5 1 1.5 2 2.5 3

Pin 22 control voltage: V_{MUTE} (V)

 $ATT - V_{MUTE}$

Figure 3 Mute Function

Figure 4 Mute Attenuation – V_{MUTE} (V)

3. AUX Input (pin 25)

The pin 25 is for input terminal of AUX amplifier.

The total gain is 0dB by using of AUX amplifier.

Therefore, the $\mu\text{-COM}$ can directly drive the AUX amplifier.

BEEP sound or voice synthesizer signal can be input to pin 25 directly.

When AUX function is not used, this pin must be connected to PRE-GND (pin 13) via a capacitor.

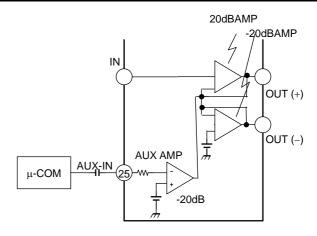


Figure 5 AUX IN

4. Prevention of speaker damage (in case of a layer short-circuit of the speaker)

When the DC resistance between the OUT+ and OUT- pins falls below 1 Ω , the output current exceeds 4 A. At this time, the protection circuit is activated to limit the current draw into the speaker. This feature prevents the speaker from being damaged, as follows:

< Speaker damaging scenario >

A DC current of over 4 V is applied to the speaker due to an external circuit failure (Note 4). (Abnormal DC output offset)

The speaker impedance becomes 1 $\boldsymbol{\Omega}$ or less due to a layer short.

A current of over 4 A flows into the speaker, damaging the speaker.

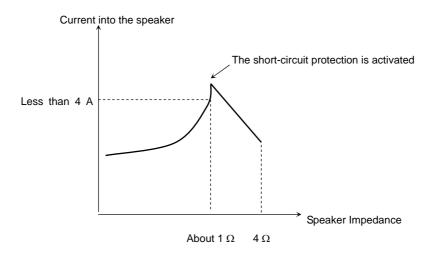


Figure 6

Note 4: An abnormal DC offset voltage is incurred when the input bias to the power IC is lost due to a leakage current from a coupling capacitor at the input or a short-circuit between the IN and adjacent lines.

5. Pop Noise Suppression

Since the TB2926HQ uses the AC-GND pin (pin 16) as the common input reference voltage pin for all amplifiers, the ratio of the input capacitance (C1) to the AC-to-GND capacitance (C6) should be 1:4. Also, if power is removed before C1 and C6 are completely charged, pop noise will be generated because of unbalanced DC currents.

To avoid this problem, it is recommended to use a larger capacitor as C2 to increase the charging times of C1 and C6. Note, however, that C2 also affects the time required from power-on to audio output.

The pop noise generated by the muting and unmuting of the audio output varies with the time constant of C4. A larger capacitance reduces the pop noise, but increases the time from when the mute control signal is applied to C4 to when the mute function is enabled.

6. External Component Constants

	Recommended		Effe	Notes	
Component Value		Purpose	When lower than recommended value		
C1	0.22 μF	To eliminate DC	Cut-off frequency is increased.	Cut-off frequency is reduced.	Pop noise is generated when V _{CC} is turned on.
C2	47 μF	To reduce ripple	Powering on/off is faster.	Powering on/off is slower.	
C3	0.1 μF	To provide sufficient oscillation margin	Reduces noise and provides s		
C4	1 μF	To reduce pop noise	High pop noise. Duration until mute function is turned on/off is short.	Low pop noise. Duration until mute function is turned on/off is long.	
C5	3900 μF	Ripple filter	Power supply humming and ripple filtering.		
C6	1 μF	Common reference voltage for all input	Pop noise is suppressed when C1: C6 = 1:4.		Pop noise is generated when V _{CC} is turned on.
C7	0.22 μF	To eliminate DC	Cut-off frequency is increased in AUX	Cut-off frequency is reduced in AUX.	

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Peak supply voltage (0.2 s)	V _{CC} (surge)	50	V
DC supply voltage	V _{CC} (DC)	25	V
Operating supply voltage	V _{CC} (opr)	18	V
Output current (peak)	I _O (peak)	9	Α
Power dissipation	P _D (Note 7)	125	W
Operating temperature	T _{opr}	-40 to 85	°C
Storage temperature	T _{stg}	-55 to 150	°C

Note 5: Package thermal resistance $\theta_{j-T} = 1^{\circ}\text{C/W}$ (typ.) (Ta = 25°C, with infinite heat sink)

The absolute maximum ratings of a semiconductor device are a set of specified parameter values that must not be exceeded during operation, even for an instant.

If any of these ratings are exceeded during operation, the electrical characteristics of the device may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed.

Moreover, any exceeding of the ratings during operation may cause breakdown, damage and/or degradation in other equipment. Applications using the device should be designed so that no absolute maximum rating will ever be exceeded under any operating conditions.

Before using, creating and/or producing designs, refer to and comply with the precautions and conditions set forth in this document.

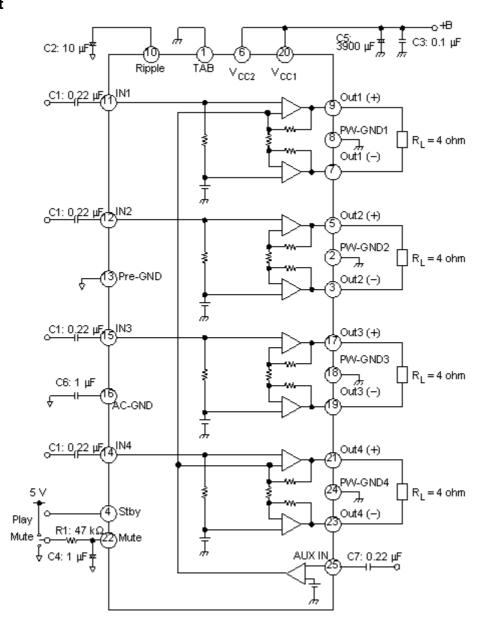
Electrical Characteristics

(V_{CC} = 13.2 V, f = 1 kHz, R_L = 4 Ω , Ta = 25°C unless otherwise specified)

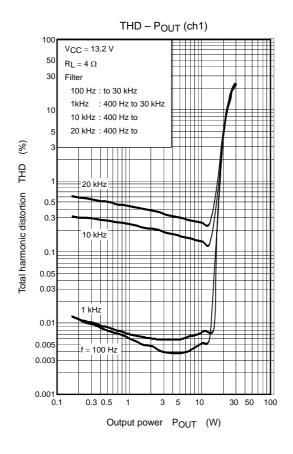
Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Quiescent supply current	I _{CCQ}	_	$V_{IN} = 0$	_	160	320	mA
Output power	P _{OUT} MAX (1)	_	V _{CC} = 15.2 V, max POWER	_	45	_	
	P _{OUT} MAX (2)	_	V _{CC} = 14.4 V, max POWER		41		
	P _{OUT} MAX (3)	_	V _{CC} = 13.7 V, max POWER		37		W
	P _{OUT} (1)	_	V _{CC} = 14.4 V, THD = 10%		24		
	P _{OUT} (2)	_	THD = 10%	19	21		
Total harmonic distortion	THD	_	P _{OUT} = 5 W		0.007	0.07	%
Voltage gain	G _V	_	V _{OUT} = 0.775 Vrms	25	26	27	dB
Channel-to-channel voltage gain	ΔG _V	_	V _{OUT} = 0.775 Vrms	-1.0	0	1.0	dB
Output noise voltage	V _{NO} (1)	_	$R_g = 0 \Omega$, DIN45405	_	60	_	μVrms
	V _{NO} (2)	_	$R_g = 0 \ \Omega$, BW = 20 Hz to 20 kHz	_	60	70	
Ripple rejection ratio	R.R.	_	$\begin{aligned} f_{rip} &= 100 \text{ Hz, } R_g = 620 \ \Omega \\ V_{rip} &= 0.775 \text{ Vrms} \end{aligned}$	50	65	_	dB
Crosstalk	C.T.	_	$R_g = 620 \Omega$ $P_{OUT} = 4 W$	_	80	_	dB
Output offset voltage	Voffset	_	_	-90	0	90	mV
Input resistance	R _{IN}	_	_	_	90	_	kΩ
Standby current	I _{SB}	_	Standby condition, V4=0,V22=0	_	0.01	1	μА
Standby control voltage	V _{SB} H	_	POWER: ON	2.9	_	VCC	V
	V _{SB} L	_	POWER: OFF	0	_	0.8	V
Mute control voltage	V _M H	_	MUTE: OFF	2.9	_	6.0	
	V _M L	_	MUTE: ON, $R_1 = 47 \text{ k}\Omega$	0	_	0.8 V	

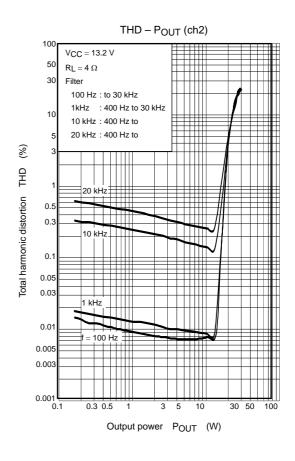
Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Mute attenuation	ATT M		MUTE: ON、DIN_AUDIO V _{OUT} = 7.75 Vrms → Mute: OFF	80	100	_	dB
Upper cut-off frequency	F _{th}	_	G _V = 26dB, -3dB	_	250	_	kHz

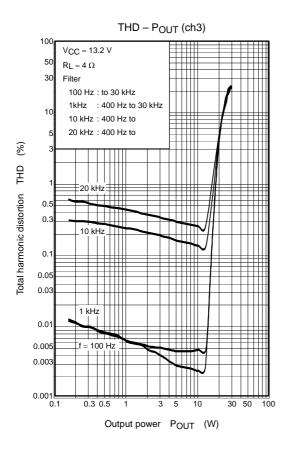
Test Circuit

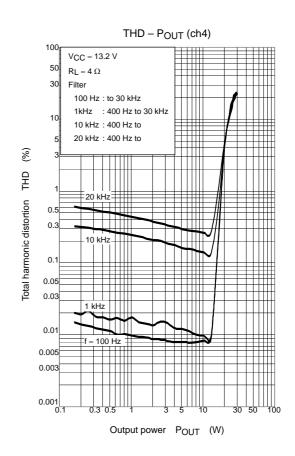


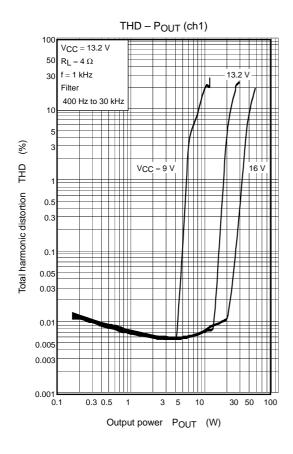
Components in the test circuit are only used to determine the device characteristics. It is not guaranteed that the system will work properly with these components.

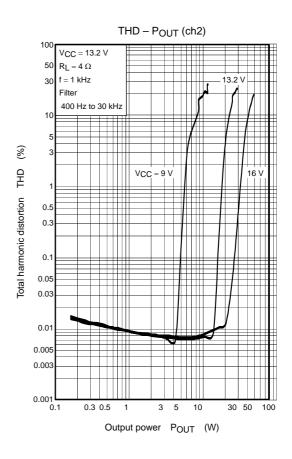


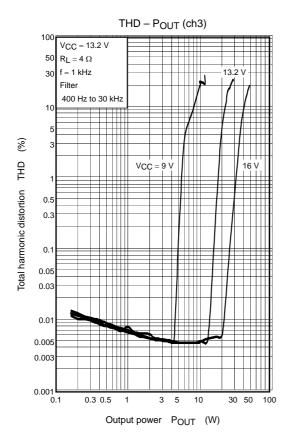


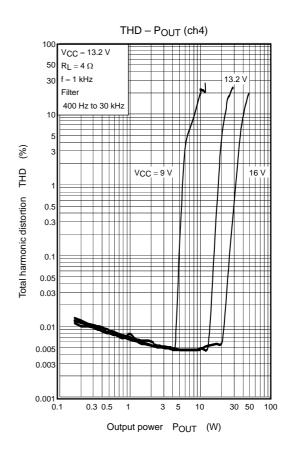


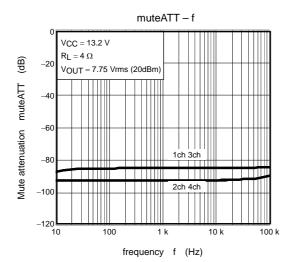


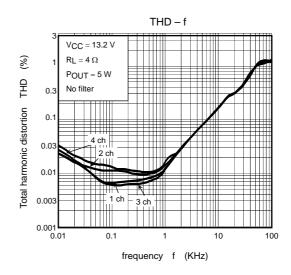


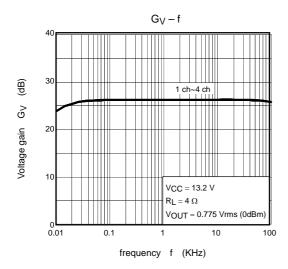


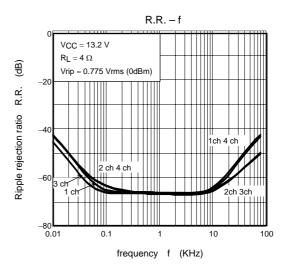


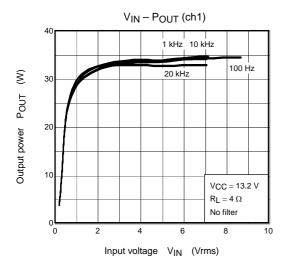


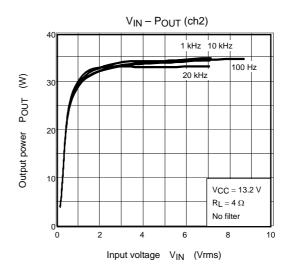


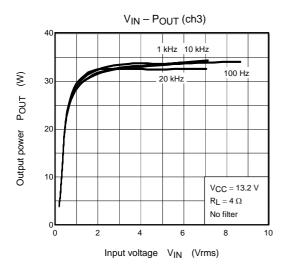


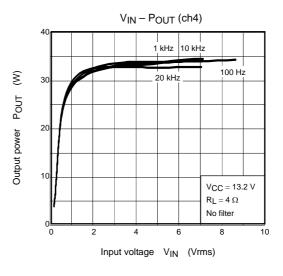


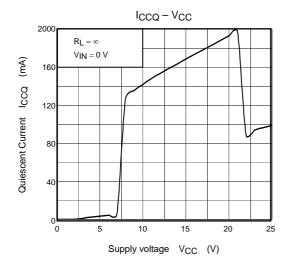


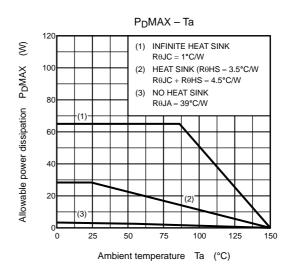


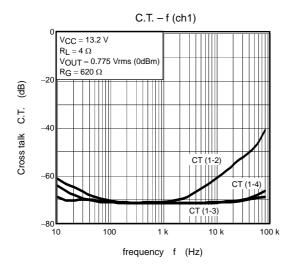


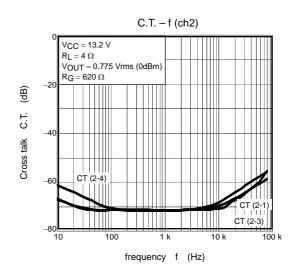


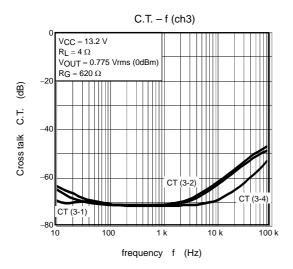


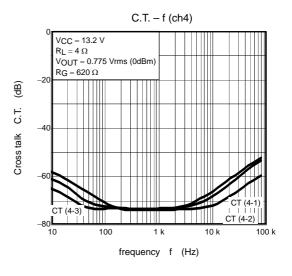


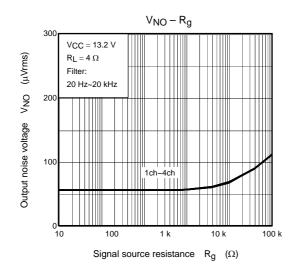


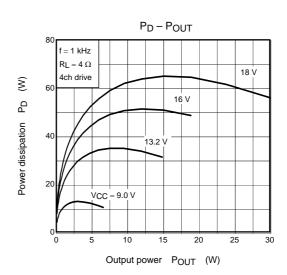






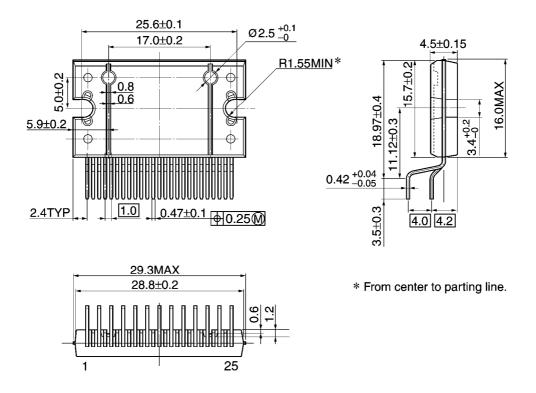






Package Dimensions

HZIP25-P-1.00F Unit: mm



Weight: 7.7 g (typ.)

- Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over
 current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute
 maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or
 load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the
 effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time
 and insertion circuit location, are required.
- If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. For details on how to connect a protection circuit such as a current limiting resistor or back electromotive force adsorption diode, refer to individual IC datasheets or the IC databook. IC breakdown may cause injury, smoke or ignition.
- Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator. If there is a large amount of leakage current such as input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure can cause smoke or ignition. (The over current can cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection type IC that inputs output DC voltage to a speaker directly.

· Over current Protection Circuit

Over current protection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the Over current protection circuits operate against the over current, clear the over current status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the over current protection circuit to not operate properly or IC breakdown before operation. In addition, depending on the method of use and usage conditions, if over current continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.

· Thermal Shutdown Circuit

Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the Thermal shutdown circuits operate against the over temperature, clear the heat generation status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the thermal shutdown circuit to not operate properly or IC breakdown before operation.

Heat Radiation Design

When using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (Tj) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.

· Installation to Heat Sink

Please install the power IC to the heat sink not to apply excessive mechanical stress to the IC. Excessive mechanical stress can lead to package cracks, resulting in a reduction in reliability or breakdown of internal IC chip. In addition, depending on the IC, the use of silicon rubber may be prohibited. Check whether the use of silicon rubber is prohibited for the IC you intend to use, or not. For details of power IC heat radiation design and heat sink installation, refer to individual technical datasheets or IC databooks.

RESTRICTIONS ON PRODUCT USE

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- The information contained herein is subject to change without notice. 021023_D
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
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- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk. 021023_B
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 021023_C
- The products described in this document are subject to the foreign exchange and foreign trade laws. 021023_E

About solderability, following conditions were confirmed

- Solderability
 - (1) Use of Sn-37Pb solder Bath
 - · solder bath temperature = 230°C
 - · dipping time = 5 seconds
 - · the number of times = once
 - · use of R-type flux
 - (2) Use of Sn-3.0Ag-0.5Cu solder Bath
 - solder bath temperature = 245°C
 - · dipping time = 5 seconds
 - · the number of times = once
 - · use of R-type flux